## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant(s):

Andrew G. Haerle, et al.

Title:

METHOD FOR TREATING SEMICONDUCTOR PROCESSING

COMPONENTS AND COMPONENTS FORMED THEREBY

Application No.: NEW APPLICATION

Filed:

**HEREWITH** 

Atty. Docket No.: 1075-E4283-DIV

MS PATENT APPLICATION COMMISSIONER FOR PATENTS PO Box 1450 Alexandria, VA 22313-1450

### INFORMATION DISCLOSURE STATEMENT TRANSMITTAL

Dear Sir:

Pursuant to 37 C.F.R. § 1.56, § 1.97 and § 1.98, the undersigned brings the patents, publications, applications or other information identified in the attached:

$\bowtie$	Form(s) PTO/SB/08A and/or PTO/SB/08B or PTO/1449
	Other: n/a

to the Examiner's attention in the above-identified application. These references were cited in parent Application No. 10/414,563, filed April 15, 2003. Accordingly, in accordance with C.F.R. §1.98(d), copies of the references are not being supplied herewith. Citation of such information shall not be construed as:

- 1. an admission that the information necessarily is, or corresponds to, prior art with respect to the instant invention;
- 2. a representation that a search has been made, other than as described below; or
- 3. an admission that the information cited herein is, or is considered to be, material to patentability as defined in § 1.56(b).

For each item of information listed that is not in the English language, the undersigned has provided a concise explanation of the relevance, such as through (i) an English language abstract, (ii) an English language equivalent application, (iii) reference to discussion in the application, or (iv) if cited in a search report or other action by a foreign patent office in a

# CERTIFICATE OF TRANSMISSION/MAILING I hereby certify that this correspondence is being facsimile transmitted to the USPTO or deposited with the United States Postal Service with sufficient postage as either First Class Mail or Express Mail, in an envelope addressed to the Commissioner for Patents on 4-21-CV

Elise K. Dougherty

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counterpart foreign application, an English language version of the search report or action that indicates the degree of relevance found by the foreign office.

# STATEMENT UNDER 37 C.F.R. § 1.704(d)

May 2	If the a 9, 2000	above-identified application is an original application filed on or after:			
	each item of information contained in this Information Disclosure S cited in a communication from a foreign patent office in a counterpand this communication was not received by any individual designated \$1.56(c) more than thirty days prior to the filing of this Information Statement.				
		FEES DUE			
	This Ir	nformation Disclosure Statement is being filed:			
		within three months of the filing date of a national application or within three months of entry of the national stage as set forth in § 1.491 in an international application. Therefore, no fee is required.			
		before the mailing date of a first Office action on the merits or before the mailing date of a first Office action after the filing of a request for continued examination under § 1.114. Therefore, no fee is believed required.			
		during the period specified in § 1.97(c). Each item of information contained in this Information Disclosure Statement was cited in a communication from a foreign patent office in a counterpart application not more than three months prior to the filing of this Information Disclosure Statement.			
		during the period specified in § 1.97(c). Accordingly, the fee set forth in § 1.17(p) is required and provided as shown on the attached Fee Transmittal.			
		during the period specified in § 1.97(d). Accordingly, the fee set forth in § 1.17(p) is required and provided as shown on the attached Fee Transmittal. Additionally, each item of information contained in this Information Disclosure Statement was cited in a communication from a foreign patent office in a counterpart application not more than three months prior to the filing of this Information Disclosure Statement.			

Should any PTO fees be necessary for entry of this Information Disclosure Statement, the undersigned hereby authorizes the Commissioner to charge Deposit Account <u>50-2469</u>.

Respectfully submitted,

Jefff**el/8/A**bel, Re<del>g.</del> No. 36,079

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# INFORMATION DISCLOSURE STATEMENT BY APPLICANT

Substitute for form 1449A/PTO

Sheet 1 of 1 (use as many sheets as necessary)
Complete if Known

Application Number: NEW APPLICATION

Filing Date: HEREWITH

First Named Inventor: Andrew G. Haerle

Group Art Unit: Examiner Name:

Attorney Docket Number: 1075-E4283-DIV

#### **U.S. PATENT DOCUMENTS**

Examiner Initials *			Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	
	AA	6,093,644		Inaba et al.	07/25/2000	
	AB	6,277,194	В	Thilderkvist et al.	08/21/2001	
	AC	6,066,572		Lu, et al.	05/23/2000	
	AD					
	AE					
	AF					
	AG				<i>'</i>	
	AH					
	ΑI					
	AJ					

### FOREIGN PATENT DOCUMENTS

Examiner	Cite	Foreign Patent	Document	Name of Patentee or	Date of	Pages,	T 6
Initials *	No.1	Office 3 Number	Kind Code 2 (if known)	Applicant of Cited Document	Publication of Cited Document MM-DD-YYYY	Columns, Lines, Where Relevant Passages or Relevant Figures Appear	
	AK			•			
	AL						
	AM						
	AN						
	AO						

### **PUBLICATIONS**

		1 002:07110110	
Examiner Initials *	Cite No.1	Title of Publication	Date of Publication of Cited Document MM-DD-YYYY
	AW	Wolf, et al., "Silicon Processing for the VLSI ERA, Volume I", PROCESS TECHNOLOGY, 1986, Lattice Press, pages 213-216.	
	AX	Ghandi, Sorab K., VLSI Fabrication Principles, Silicon and Gallium Aresnide, 1983, John Wiley and Sons, pages 517-520.	
	AY		
	AZ		

Examiner		Date	
Signature	<u> </u>	Considered	

<sup>\*</sup>EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

<sup>1</sup> Unique citation designation number. 2 See attached Kinds of U.S. Patent Documents. 3 Enter Office that issued the document, by the twoletter code (WIPO Standard ST.3). 4 For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. 5 Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. 6 Applicant is to place a check mark here if English language Translation is attached.